

FDG901D

Slew Rate Control IC for P-Channel MOSFETs

Features

- Three Programmable Slew Rates
- Reduces Inrush Current
- Minimizes EMI
- Normal Turn-Off Speed
- Low-Power CMOS Operates Over Wide Voltage Range
- Compact Industry Standard SC70-5 Surface Mount Package
- RoHS Compliant

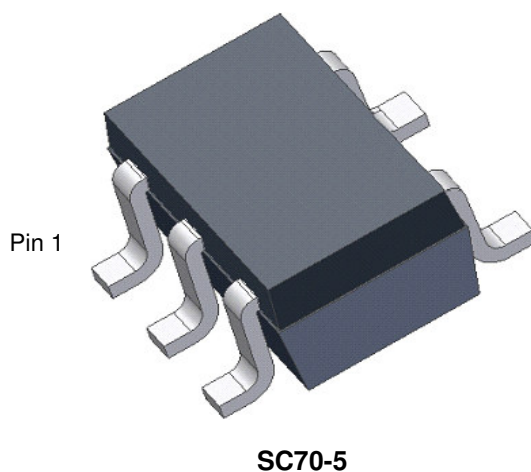
Applications

- Battery Load switch
- Power management



General Description

The FDG901D is specifically designed to control the turn on of a P-Channel MOSFET in order to limit the inrush current in battery switching applications with high capacitance loads. During turn-on, the FDG901D drives the MOSFET's gate low with a regulated current source, thereby controlling the MOSFET's turn on. For turn-off, the IC pulls the MOSFET gate up quickly for efficient turn off.

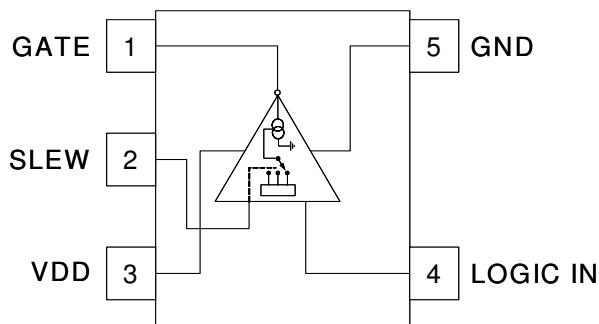


SC70-5

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape Width	Quantity
91	FDG901D	7"	8mm	3000 units

Pin Configuration



Absolute Maximum Ratings

Parameter	Min.	Max.	Unit
Supply Voltage	-0.5	10	V
DC Input Voltage (Logic Inputs)	-0.7	9	V
Power Dissipation for Single Operation @ 85°C		150	mW
Operating and Storage Junction Temperature	-65	150	°C
Thermal Resistance, Junction to Ambient (note 1)		425	°C/W

Recommended Operating Range

Parameter	Min.	Max.	Unit
Supply Voltage	2.7	6	V
Operating Junction Temperature	-40	150	°C

Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

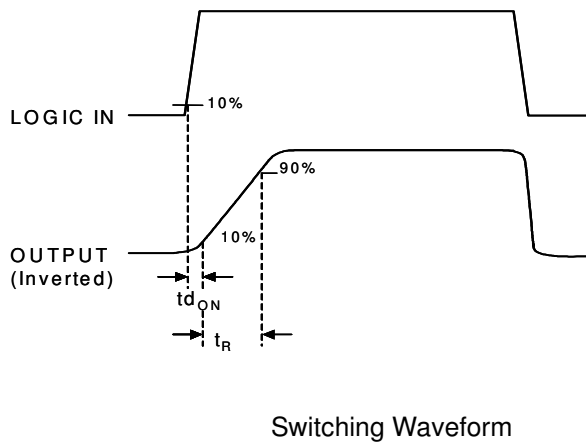
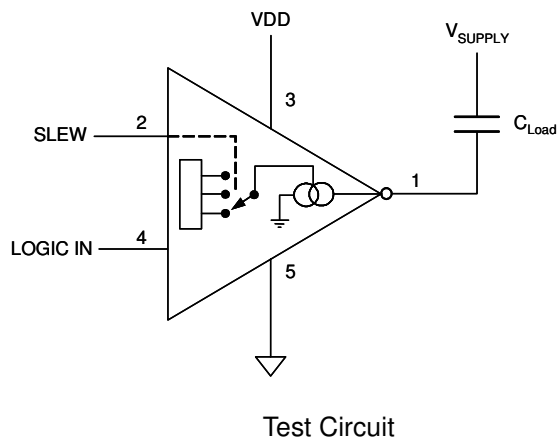
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Logic Levels						
Logic High Input Voltage	V_{IH}	$V_{DD} = 2.7\text{V to } 6.0\text{V}$	2.55			V
Logic Low Input Voltage	V_{IL}	$V_{DD} = 2.7\text{V to } 6.0\text{V}$			2.0	V
Off Characteristics - Slew Rate Control Driver						
Supply Input Breakdown Voltage	BV_{DG}	$I_{DG} = 10\mu\text{A}$, $V_{IN} = 0\text{V}$, $V_{SLEW} = 0\text{V}$	9			V
Slew Input Breakdown Voltage	BV_{SLEW}	$I_{SLEW} = 10\mu\text{A}$, $V_{IN} = 0\text{V}$	9			V
Logic Input Breakdown Voltage	BV_{IN}	$I_{IN} = 10\mu\text{A}$, $V_{SLEW} = 0\text{V}$	9			V
Supply Input Leakage Current	IR_{DG}	$V_{DG} = 8\text{V}$, $V_{IN} = 0\text{V}$, $V_{SLEW} = 0\text{V}$			100	nA
Slew Input Leakage Current	IR_{SLEW}	$V_{SLEW} = 8\text{V}$, $V_{IN} = 0\text{V}$			100	nA
Logic Input Leakage Current	IR_{IN}	$V_{IN} = 8\text{V}$, $V_{SLEW} = 0\text{V}$			100	nA
On Characteristics - Slew Rate Control Driver						
Gate Current	I_G	$V_{IN} = 6\text{V}$, $V_{GATE} = 2\text{V}$	Slew Pin = Open		90	120 μA
			Slew Pin = GND		1	10 μA
			Slew Pin = V_{DD}		10	50 nA

Notes: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.

Electrical Characteristics Cont.

$T_A = 25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
P-Channel Switching Times ($V_{\text{SUPPLY}} = 5.5\text{V}$, $V_{\text{DD}} = 5.5\text{V}$, Logic IN = 5.5V, $C_{\text{LOAD}} = 510\text{pF}$, Test Circuit)						
Delay On Time	t_{dON}	Slew Pin = Open		8.3		μs
		= GND		0.6		ms
		= V_{DD}		2.2		ms
V_{OUT} Rise Time	t_{R}	= Open		28		μs
		= GND		1.8		ms
		= V_{DD}		11		ms
Output Slew Rate	dv/dt	= Open		162		V/ms
		= GND		26		V/ms
		= V_{DD}		0.3		V/ms



Typical Characteristics

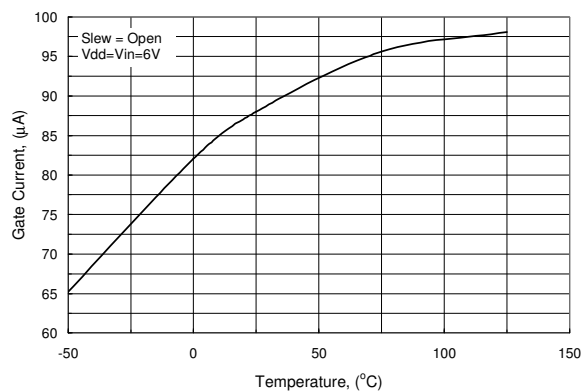


Figure 1. Gate Output Current vs. Temperature (SLEW = OPEN)

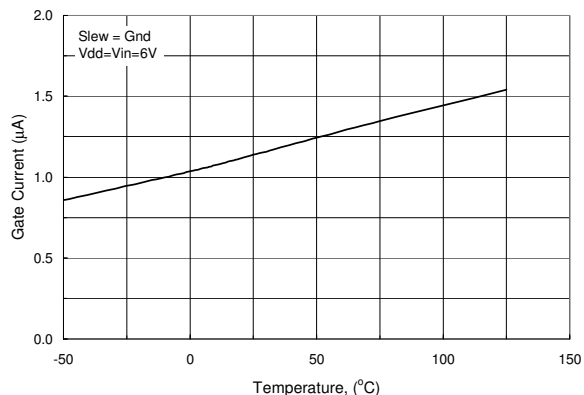


Figure 2. Gate Output Current vs. Temperature (SLEW = GROUND)

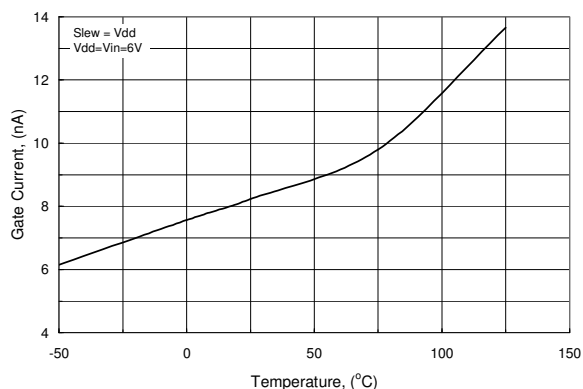


Figure 3. Gate Output Current vs. Temperature (SLEW = V_{DD})

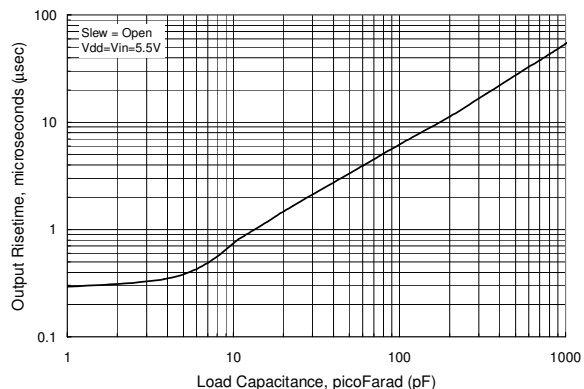


Figure 4. t_{RISE} vs. Load Capacitance (SLEW = OPEN)

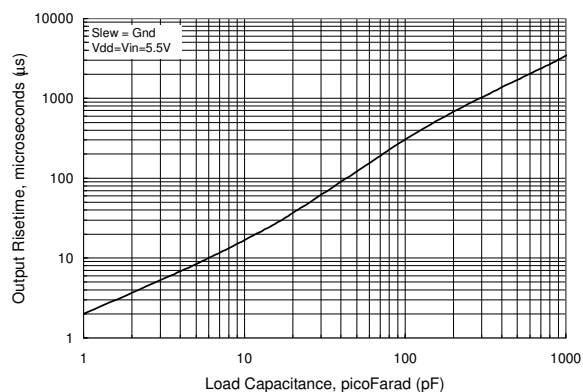


Figure 5. t_{RISE} vs. Load Capacitance (SLEW = GROUND)

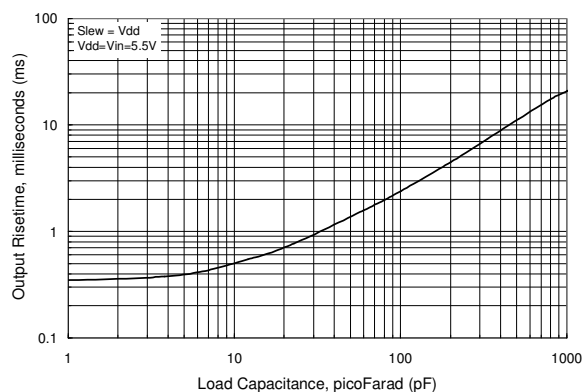


Figure 6. t_{RISE} vs. Load Capacitance (SLEW = V_{DD})

Typical Characteristics

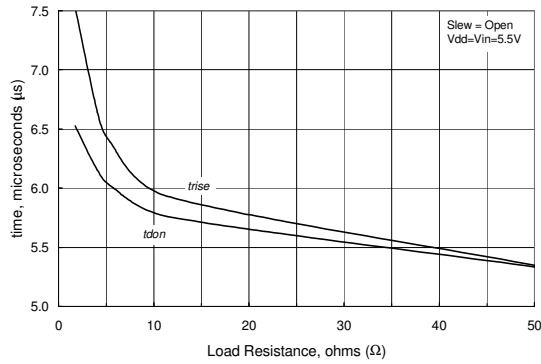


Figure 7. Switching Time vs. Load Resistance (SLEW = OPEN)

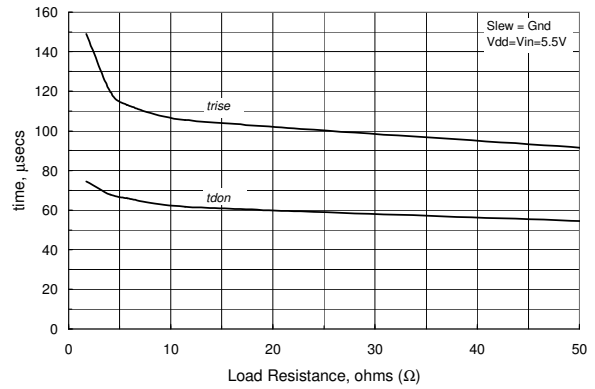


Figure 8. Switching Time vs. Load Resistance (SLEW = GROUND)

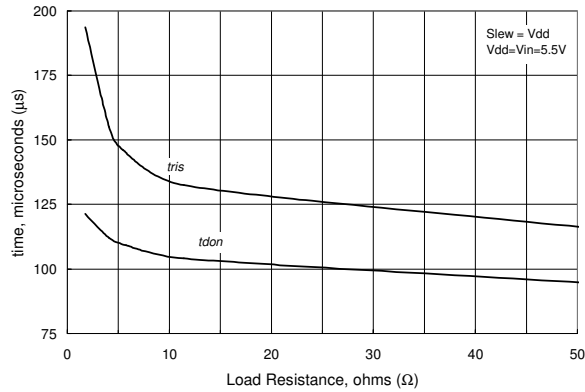


Figure 9. Switching Time vs. Load Resistance (SLEW = VDD)

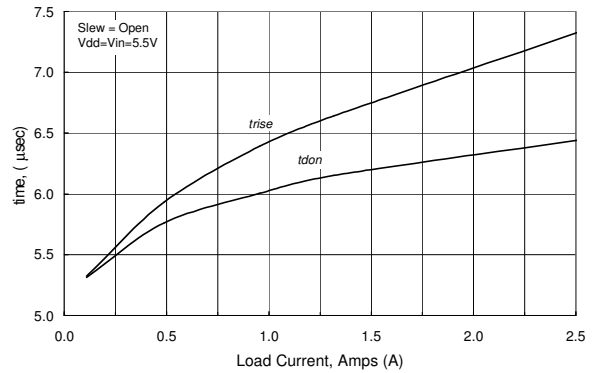


Figure 10. Switching Time vs. Load Current (SLEW = OPEN)

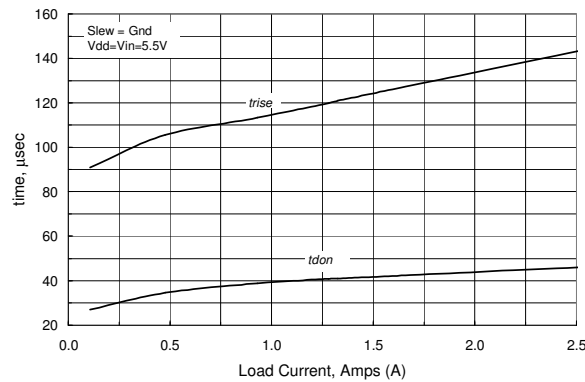


Figure 11. Switching Time vs. Load Current (SLEW = GROUND)

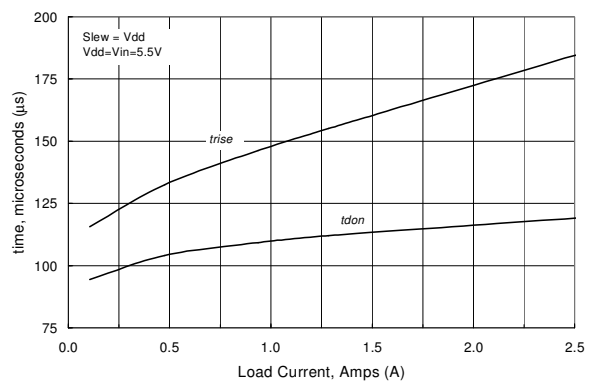
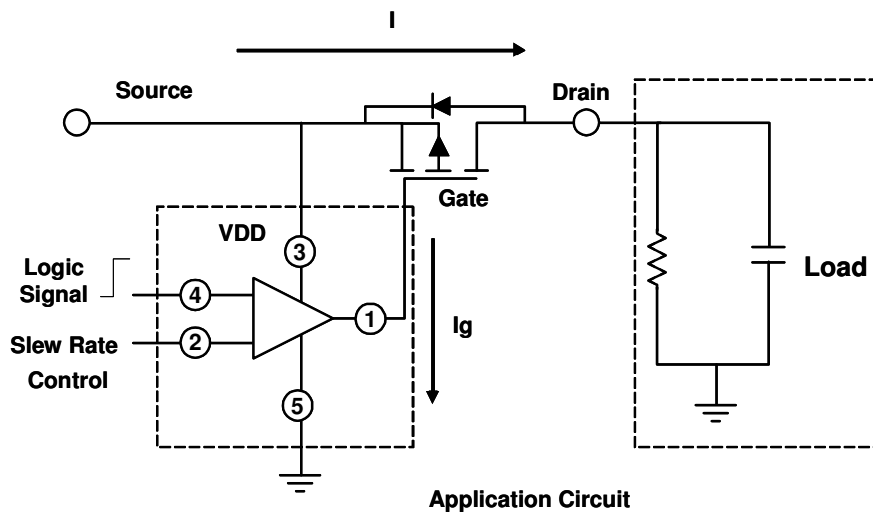


Figure 12. Switching Time vs. Load Current (SLEW = VDD)

Application Information

Typical Application



Battery powered systems make extensive usage of load switching, turning the power to subsystems off, in order to extend battery life. Power MOSFETs are used to accomplish this task. In PDA's and Cell phones, these MOSFETs are usually low threshold P-Channels. Since the loads typically include bypass capacitor components (high capacitive component), a high inrush current can occur when the load is switched on. This inrush current can cause transients on the main power supply disturbing circuitry supplied by it.

The simplest method of limiting the inrush current is to control the slew rate of the MOSFET switch. This can be done with external R/C circuits, but this approach can occupy significant PCB area, and involves other compromises in performance. The slew rate control driver IC FDG901D is specifically designed to interface low voltage digital circuitry with power MOSFETs and reduce the rapid inrush current in load switch applications. The IC limits inrush current by controlling the current, which drives the gate of the P-Channel MOSFET switch.

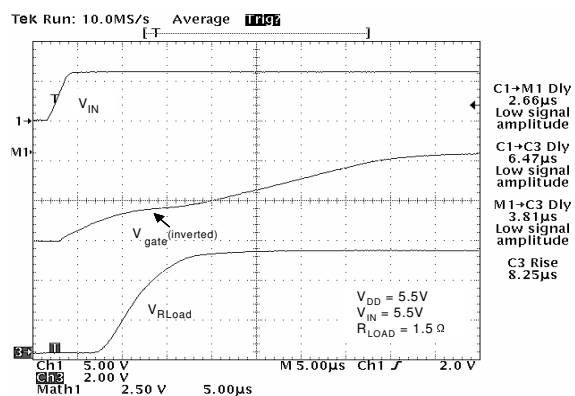
The control input is a CMOS compatible input with a minimum high input voltage of 2.55V with a power rail voltage of 6V. Therefore, it is compatible with any CMOS logic voltages between 2.55V and 5V and under these conditions there is no additional configuration required.

The Slew Rate Control Driver (FDG901D) is designed to give a programmed choice of one of three steady dv/dt states on the output during turn-on. To change the dv/dt value, the user needs to use the Slew Rate Control Pin (Pin 2). To utilize the smallest current setting (10 nA) from the IC, a voltage equal to V_{DD} must be applied to the Slew Rate Control Pin 2. To use the next higher current setting (~1μA) a voltage equal to Ground must be applied to Pin 2. To achieve the highest current setting (~80μA) or obtain a faster switching speed, the Slew Rate Pin2 must be open (floating). A higher value of capacitance will result in a slower switching rate. To determine the switching times of each setting use the simple equation:

$$t = \frac{Q_g}{I_G}$$

where Q_g is the Gate charge in nC for a given MOSFET and I_G is the gate current controlled by the slew rate pin.

Below is a captured image from an oscilloscope depicting the device response. The FDG901D was connected to control an FDG258P P-Channel DMOS. The Slew Rate control pin was set to open (floating state).



Circuit waveforms for an FDG901D controlling a P-Channel FDG258P MOFET



TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

ACEx®	FPST™	PDP-SPM™	SupreMOS™
Build it Now™	FRFET®	Power220®	SyncFET™
CorePLUS™	Global Power Resource™	POWEREDGE®	SYSTEM GENERAL®
CROSSVOLT™	Green FPS™	Power-SPM™	The Power Franchise®
CTL™	Green FPS™ e-Series™	PowerTrench®	the power franchise
Current Transfer Logic™	GTO™	Programmable Active Droop™	TinyBoost™
EcoSPARK®	i-Lo™	QFET®	TinyBuck™
EZSWITCH™ *	IntelliMAX™	QST™	TinyLogic®
	ISOPLANAR™	QT Optoelectronics™	TINYOPTO™
	MegaBuck™	Quiet Series™	TinyPower™
Fairchild®	MICROCOUPLER™	RapidConfigure™	TinyPWM™
Fairchild Semiconductor®	MicroFET™	SMART START™	TinyWire™
FACT Quiet Series™	MicroPak™	SPM®	μSerDes™
FACT®	MillerDrive™	STEALTH™	UHC®
FAST®	Motion-SPM™	SuperFET™	Ultra FRFET™
FastvCore™	OPTOLOGIC®	SuperSOT™-3	UniFET™
FlashWriter® *	OPTOPLANAR®	SuperSOT™-6	VCX™
		SuperSOT™-8	

* EZSWITCH™ and FlashWriter® are trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild Semiconductor. The datasheet is printed for reference information only.

Rev. I33



О компании

ООО "ТрейдЭлектроникс" - это оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов. Реализуемая нашей компанией продукция насчитывает более полумиллиона наименований.

Благодаря этому наша компания предлагает к поставке практически не ограниченный ассортимент компонентов как оптовыми, мелкооптовыми партиями, так и в розницу.

Наличие собственной эффективной системы логистики обеспечивает надежную поставку продукции по конкурентным ценам в точно указанные сроки.

Срок поставки со стоков в **Европе и Америке – от 3 до 14 дней.**

Срок поставки из **Азии – от 10 дней.**

Благодаря развитой сети поставщиков, помогаем в поиске и приобретении экзотичных или снятых с производства компонентов.

Предоставляем спец цены на элементы для создания инженерных сэмплов.

Упорный труд, качественный результат дают нам право быть уверенными в себе и надежными для наших клиентов.

Наша компания это:

- Гарантия качества поставляемой продукции
- Широкий ассортимент
- Минимальные сроки поставок
- Техническая поддержка
- Подбор комплектации
- Индивидуальный подход
- Гибкое ценообразование

Наша организация особенно сильна в поставках модулей, микросхем, пассивных компонентов, ксайленсах (XC), EPF, EPM и силовой электроники.

Большой выбор предлагаемой продукции, различные виды оплаты и доставки, позволят Вам сэкономить время и получить максимум выгоды от сотрудничества с нами!

Перечень производителей, продукцию которых мы поставляем на российский рынок





Trade Electronics.ru

гарантия бесперебойности производства и
качества выпускаемой продукции

С удовольствием будем прорабатывать для Вас поставки всех необходимых компонентов по текущим запросам для скорейшего выявления групп элементов, по которым сотрудничество именно с нашей компанией будет для Вас максимально выгодным!

С уважением,

Менеджер отдела продаж ООО

«Трейд Электроникс»

Шишлаков Евгений

8 (495)668-30-28 доб 169

manager28@tradeelectronics.ru

<http://www.tradeelectronics.ru/>